

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









Rev. V22

Features

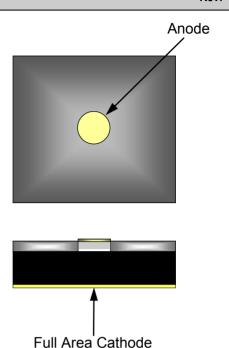
- Switch & Attenuator Die
- Extensive Selection of I-Region Lengths
- Hermetic
- Glass Passivated Cermachip
- Oxide Passivated Planar Chips
- Voltage Ratings to 3000 V
- · Fast Switching Speed
- Low Loss
- High Isolation
- RoHS* Compliant

Description

MACOM offers a comprehensive line of low capacitance, planar and mesa, silicon PIN diode chips which use ceramic glass and silicon nitride passivation technology. The silicon PIN chip series of devices cover a broad spectrum of performance requirements for control circuit applications. They are available in several choices of I-region lengths and have been optimally designed to minimize parametric trade offs when considering low capacitance, low series resistance, and high breakdown voltages. Their small size and low parasitics, make them an ideal choice for broadband, high frequency, micro-strip hybrid assemblies.

The attenuator line of PIN diode chips are a planar or mesa construction and because of their thicker I-regions and predictable $R_{\rm S}$ vs. I characteristics, they are well suited for low distortion attenuator and switch circuits. Incorporated in the chip's construction is MACOM's, time proven, hard glass, Cermachip process. The hard glass passivation completely encapsulates the entire PIN junction area resulting in a hermetically sealed chip which has been qualified in many military applications. These Cermachip diodes are available in a wide range of voltages, up to 3,000 volts, which are capable of controlling kilowatts of RF power.

Many of MACOM's silicon PIN diode chips are also available in several different package styles. Please refer to the "Packaged PIN Diode Datasheet" for case style availability and electrical specifications located on the MACOM website. Also for high voltage, high power devices refer to MA4PK2000.



Absolute Maximum Ratings¹ T_A = +25°C (Unless otherwise specified)

•			
Parameter	Absolute Maximum		
Forward Current (I _F)	Per P/N R _s vs. I Graph		
Reverse Voltage (V _R)	Per Specification Table		
Power Dissipation (W)	175°C – T _{ambient} °C Theta		
Operating Temperature	-55°C to +175°C		
Storage Temperature	-55°C to +200°C		
Junction Temperature	+175°C		
Mounting Temperature	+320°C for 10 seconds		

Exceeding these limits may cause permanent damage to the chip

^{*} Restrictions on Hazardous Substances, European Union Directive 2011/65/EU.



Rev. V22

Electrical Specifications: T_A = +25°C

Low Capacitance PIN

	Maximum Characteristics			Nominal Characteristics			
Part Number	Reverse Voltage² V _R <10 μA	Capacitance 1 MHz C _J @ -10 V	Series Res. 500 MHz R _s @ 10 mA	Carrier Lifetime³ T _L	Reverse Recovery Time ⁴ T _{RR}	l Region Length	Theta
•	VDC	pF	Ω	ηs	ηѕ	μm	°C/W
MA4P161-134	100	0.10	1.50	150	15	13	65
MA4P203-134	100	0.15	1.50	150	25	13	75
MA4P7493-134	150	0.05	1.80	80	8	19	60
MADP-000165-01340W	200	0.06	2.50	200	20	19	30
MADP-000135-01340W	200	0.15	1.20	440	44	19	30

Attenuator PIN

	Maxir	Maximum Characteristics			Nominal Characteristics				
Part Number	Reverse Voltage ² V _R <10 µA	Capacitance 1 MHz C _J @ -100 V	Series Res. 100 MHz R _S @ 10 mA	Carrier Lifetime ³ T _L	Series Res. 100 MHz R _s @ 10 µA	Series Res. 100 MHz R _s @ 1 mA	I Region Length	Theta	
	V _{DC}	pF	Ω	μs	Ω	Ω	mils	°C/W	
MA47416-132	200	0.15	6	2	2000	30	4	30	
MA47418-134	200	0.15	3	1	500	15	2	25	

^{2.} Reverse Voltage (V_R) is sourced and the resultant reverse leakage current (I_R) is measured to be <10 μ A.

^{3.} Nominal carrier life time (T_L) specified at I_F = + 10 mA , I_{REV} = - 6 mA.

^{4.} Nominal reverse recovery time specified at I_F = + 20 mA , I_{REV} = - 200 mA.



Rev. V22

Electrical Specifications: $T_A = +25$ °C (cont.)

Cermachip PIN

Maximum Characteristics		Nominal Characteristics				
Part Number	Reverse Voltage ⁵ V _R <10 μA	Capacitance 1 MHz C _J @ -100 V	Series Res. 100 MHz R _s @ 100 mA	Carrier Lifetime ⁶	l Region Length	Theta
	V _{DC}	pF	Ω	μs	μm	°C/W
MA4P303-134	200	0.15 @ 10 V	1.5 @ 10 mA ⁸	0.3	20	30
MA4P404-132	250	0.20 @ 50 V	0.70 @ 50 mA ⁸	0.6	30	20
MA4P504-132	500	0.20	0.60	1	50	20
MA4P505-131	500	0.35	0.45	2	50	14
MA4P506-131	500	0.70	0.30	3	50	11
MADP-000488-13740W	900	0.19 @ 50 V	1.6 @ 50 mA	4	140	45
MA4P604-131	1000	0.30	1.00	3	90	10
MA4P606-131	1000	0.60	0.70	4	90	8
MA4P607-212	1000	1.30	0.40	12	127	4
MA4PK3000-1252 ⁷	3000	2.90	0.25 @ 500 mA ⁹	60	350	1.5

^{5.} Reverse Voltage (V_R) is sourced and the resultant reverse leakage current (I_R) is measured to be <10 μ A.

^{6.} Nominal carrier life time (T_L) specified at $I_F = +10$ mA, $I_{REV} = -6$ mA.

^{7.} Upon completion of circuit installation, the chip must be covered with a dielectric conformal coating such as SYLGARD 539® to prevent voltage arcing.

^{8.} Test Frequency = 500 MHz

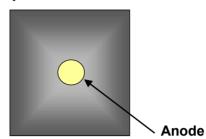
^{9.} Test Frequency = 4 MHz



Rev. V22

Chip Dimensions





Low Capacitance PIN Chip

	Nominal Characteristics (mils.)				
Part Number	Anode Diameter ± 0.5	Chip Size ± 0.5	Chip Thickness ± 0.5		
MA4P161-134	3.5	13 x 13	6.0		
MA4P203-134	3.1	13 x 13	6.0		
MA4P7493-134	3.8	13 x 13	6.5		
MADP-000165-01340W	1.8	13 x 13	7.0		
MADP-000135-01340W	3.1	13 x 13	10.0		

Attenuator PIN Chip

	Nominal Characteristics (mils.)				
Part Number	Anode Diameter ± 0.5	Chip Size ± 2.0	Chip Thickness ± 1.0		
MA47416-132	7.5x7.5 ¹⁰	19 x 19	7.0		
MA47418-134	7.5	13 x 13	7.0		

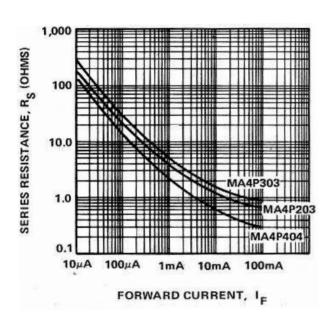
^{10.} Anode top contact is square.

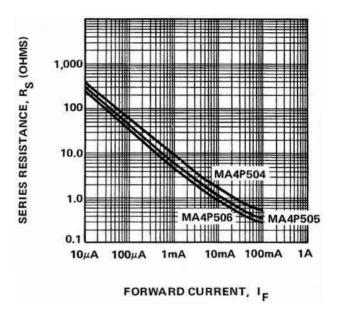
Cermachip PIN Chip

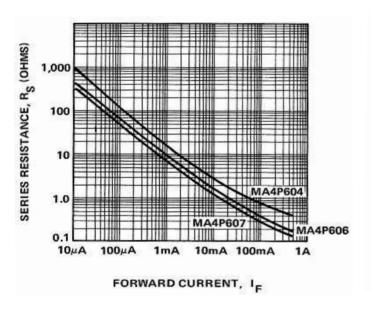
	Nomir	Nominal Characteristics (mils.)				
Part Number	Anode Diameter ± 0.5	Chip Size ± 2.0	Chip Thickness ± 1.0			
MA4P303-134	3.0	13 x 13	10.0			
MA4P404-132	6.8	20 x 20	10.0			
MA4P504-132	6.8	20 x 20	10.0			
MA4P505-131	13.0	27 x 27	11.0			
MA4P506-131	15.8	27 x 27	12.0			
MADP-000488-13740W	12.2	23 x 23	13.5			
MA4P604-131	17.0	27 x 27	13.5			
MA4P606-131	21.0	32 x 32	14.0			
MA4P607-212	37.0	62 x 62	18.5			
MA4PK3000-1252	85.0	172 x 172	28.0			

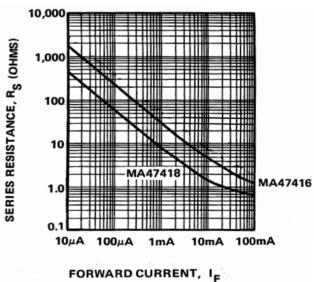
Rev. V22

Typical Series Resistance vs. Forward Current Performance







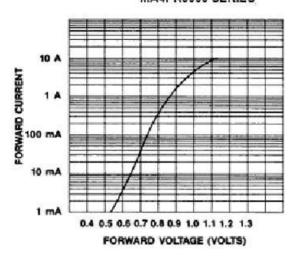




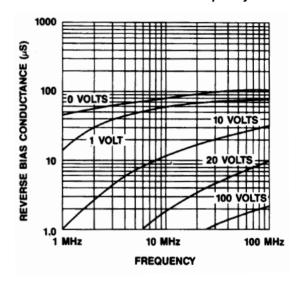
Rev. V22

MA4PK3000 (3kV) Chip

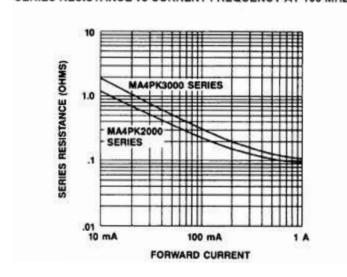
DC FORWARD VOLTAGE V5 FORWARD CURRENT MA4PK3000 SERIES



Reverse Bias Conductance vs. Frequency and



SERIES RESISTANCE V5 CURRENT FREQUENCY AT 100 MHz





Rev. V22

Die Handling and Bonding Information

Handling:

All semiconductor chips should be handled with care to avoid damage or contamination from perspiration, salts, and skin oils. The use of plastic tipped tweezers or vacuum pickup is strongly recommended for the handling and placing of individual components. Bulk handling should ensure that abrasion and mechanical shock are minimized.

Die Attach Surface:

Die can be mounted with an 80Au/Sn20, eutectic solder preform, RoHS compliant solders or electrically conductive silver epoxy. The metal RF and DC ground plane mounting surface must be free of contamination and should have a surface flatness of $< \pm 0.002$ ".

Eutectic Die Attachment Using Hot Gas Die Bonder:

A work surface temperature of 255°C is recommended. When hot forming gas (95%N/5%H) is applied, the work area temperature should be approximately 290°C. The chip should not be exposed to temperatures greater than 320°C for more than 10 seconds.

Eutectic Die Attachment Using Reflow Oven:

For recommended reflow profile refer to Application Note 538 "Surface Mounting Instructions",

Electrically Conductive Epoxy Die Attachment:

A controlled amount of electrically conductive, silver epoxy, approximately 1 - 2 mils in thickness, should be used to minimize ohmic and thermal resistance. A thin epoxy fillet should be visible around the perimeter of the chip after placement to ensure full area coverage. Cure conductive epoxy per manufacturer's schedule. Typically 150°C for 1 hour.

Wire and Ribbon Bonding:

The die anode bond pads have a Ti-Pt-Au metallization scheme, with a final gold thickness of 1.0 micron. Thermo-compression or thermo-sonic wedge bonding of either gold wire or ribbon is recommended. A bonder heat stage temperature setting of 200°C, tool tip temperature of 150°C and a force of 18 to 50 grams is suggested. Ultrasonic energy may also be used but should be adjusted to the minimum amplitude required to achieve an acceptable bond. Excessive energy may cause the anode metallization to separate from the chip. Automatic ball or wedge bonding may also be used.

For more detailed handling and assembly instructions, see <u>Application Note M541</u>, "Bonding and Handling Procedures for Chip Diode Devices".



Rev. V22

M/A-COM Technology Solutions Inc. All rights reserved.

Information in this document is provided in connection with M/A-COM Technology Solutions Inc ("MACOM") products. These materials are provided by MACOM as a service to its customers and may be used for informational purposes only. Except as provided in MACOM's Terms and Conditions of Sale for such products or in any separate agreement related to this document, MACOM assumes no liability whatsoever. MACOM assumes no responsibility for errors or omissions in these materials. MACOM may make changes to specifications and product descriptions at any time, without notice. MACOM makes no commitment to update the information and shall have no responsibility whatsoever for conflicts or incompatibilities arising from future changes to its specifications and product descriptions. No license, express or implied, by estoppels or otherwise, to any intellectual property rights is granted by this document.

THESE MATERIALS ARE PROVIDED "AS IS" WITHOUT WARRANTY OF ANY KIND, EITHER EXPRESS OR IMPLIED, RELATING TO SALE AND/OR USE OF MACOM PRODUCTS INCLUDING LIABILITY OR WARRANTIES RELATING TO FITNESS FOR A PARTICULAR PURPOSE, CONSEQUENTIAL OR INCIDENTAL DAMAGES, MERCHANTABILITY, OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT. MACOM FURTHER DOES NOT WARRANT THE ACCURACY OR COMPLETENESS OF THE INFORMATION, TEXT, GRAPHICS OR OTHER ITEMS CONTAINED WITHIN THESE MATERIALS. MACOM SHALL NOT BE LIABLE FOR ANY SPECIAL, INDIRECT, INCIDENTAL, OR CONSEQUENTIAL DAMAGES, INCLUDING WITHOUT LIMITATION, LOST REVENUES OR LOST PROFITS, WHICH MAY RESULT FROM THE USE OF THESE MATERIALS.

MACOM products are not intended for use in medical, lifesaving or life sustaining applications. MACOM customers using or selling MACOM products for use in such applications do so at their own risk and agree to fully indemnify MACOM for any damages resulting from such improper use or sale.